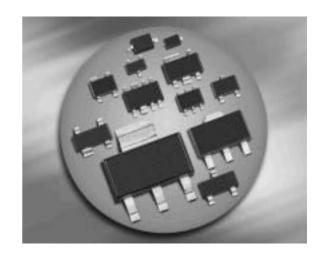


### **Silicon Switching Diode**

- For high-speed switching applications
- Common cathode configuration
- BAV70S / U: For orientation in reel see package information below



#### BAV70 BAV70T BAV70W

BAV70S BAV70U





Туре	Package	Configuration	Marking
BAV70	SOT23	common cathode	A4s
BAV70S	SOT363	double common cathode	A4s
BAV70T	SC75	common cathode	A4
BAV70U	SC74	double common cathode	A4s
BAV70W	SOT323	common cathode	A4s



**Maximum Ratings** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_{R}$	80	V
Peak reverse voltage	$V_{RM}$	85	
Forward current	l <sub>F</sub>	200	mA
Non-repetitive peak surge forward current	I <sub>FSM</sub>		А
$t = 1 \mu s$		4.5	
t = 1  ms		1	
t = 1 s single		0.5	
t = 1 s double		0.75	
Total power dissipation	P <sub>tot</sub>		mW
BAV70, <i>T</i> <sub>S</sub> ≤ 33°C		250	
BAV70S, <i>T</i> <sub>S</sub> ≤ 85°C		250	
BAV70T, <i>T</i> <sub>S</sub> ≤ 73°C		250	
BAV70U, <i>T</i> <sub>S</sub> ≤ 90°C		250	
BAV70W, $T_S \le 103^{\circ}C$		250	
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-65 150	

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	$R_{thJS}$		K/W
BAV70		≤ 460	
BAV70S		≤ 260	
BAV70T		≤ 310	
BAV70U		≤ 240	
BAV70W		≤ 190	

 $<sup>^{\</sup>rm 1}{\rm For}$  calculation of  $R_{\rm thJA}$  please refer to Application Note Thermal Resistance

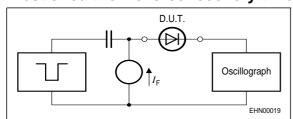


**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol		Unit			
		min.	typ.	max.		
DC Characteristics			1		i	
Breakdown voltage	$V_{(BR)}$	85	-	-	V	
$I_{(BR)} = 100  \mu A$						
Reverse current	I <sub>R</sub>				μΑ	
$V_{R} = 70 \text{ V}$		-	-	0.15		
$V_{R} = 25 \text{ V}, T_{A} = 150 \text{ °C}$		-	-	30		
$V_{R} = 70 \text{ V}, \ T_{A} = 150 \text{ °C}$		-	-	50		
Forward voltage	V <sub>F</sub>				mV	
$I_{F} = 1 \; mA$		-	-	715		
$I_{\rm F} = 10 \; {\rm mA}$		-	-	855		
$I_{\rm F}$ = 50 mA		-	-	1000		
$I_{\rm F} = 100 \; {\rm mA}$		-	-	1200		
$I_{\rm F} = 150 \; {\rm mA}$		-	-	1250		
AC Characteristics	•					
Diode capacitance	C <sub>T</sub>	-	-	1.5	pF	
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}$						
Reverse recovery time	t <sub>rr</sub>	-	-	4	ns	
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 10 mA, measured at $I_{\rm R}$ = 1mA ,						
$R_{L} = 100 \ \Omega$						

3

### Test circuit for reverse recovery time



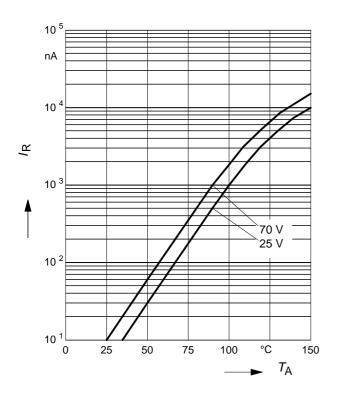
Pulse generator:  $t_{\rm p}$  = 100ns, D = 0.05,  $t_{\rm r}$  = 0.6ns,  $R_{\rm i}$  = 50 $\Omega$ 

Oscillograph:  $R = 50\Omega$ ,  $t_r = 0.35$ ns, C = 0.05pF



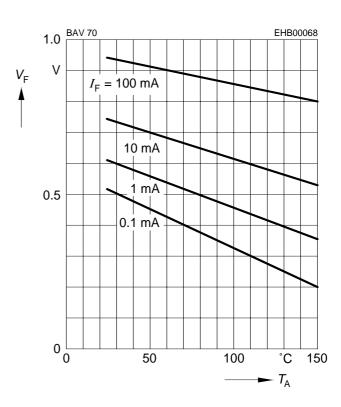
# Reverse current $I_R = f(T_A)$

 $V_{R}$  = Parameter



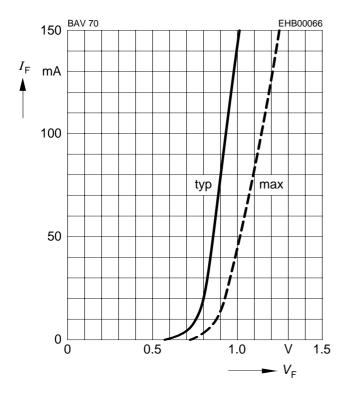
# Forward Voltage $V_F = f(T_A)$

 $I_{\mathsf{F}} = \mathsf{Parameter}$ 



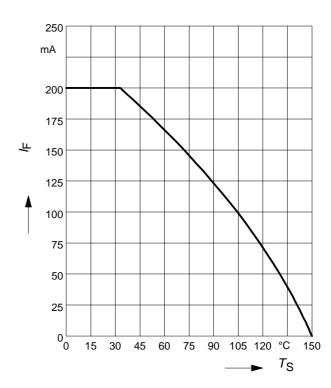
# Forward current $I_F = f(V_F)$

 $T_{\mathsf{A}} = 25^{\circ}\mathsf{C}$ 



# Forward current $I_F = f(T_S)$

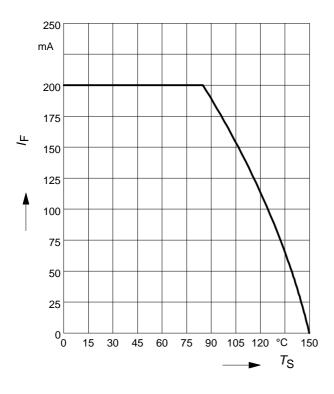
BAV70





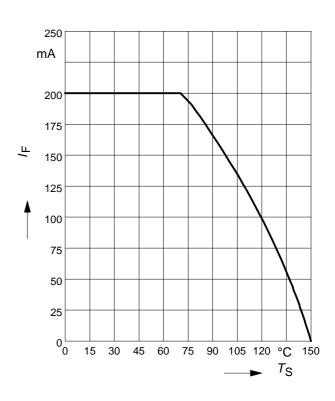
# Forward current $I_F = f(T_S)$

BAV70S



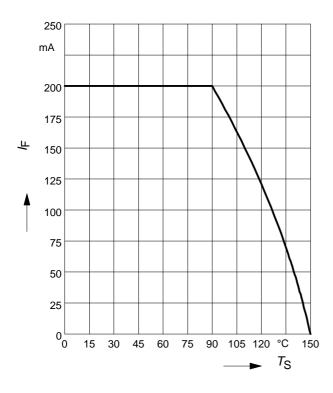
# Forward current $I_F = f(T_S)$

BAV70T



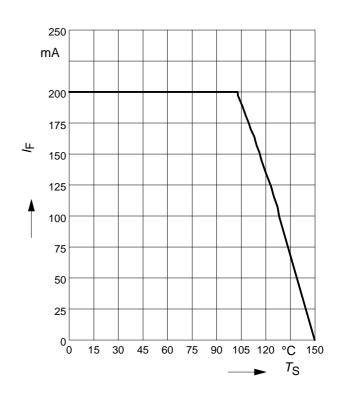
# Forward current $I_F = f(T_S)$

BAV70U



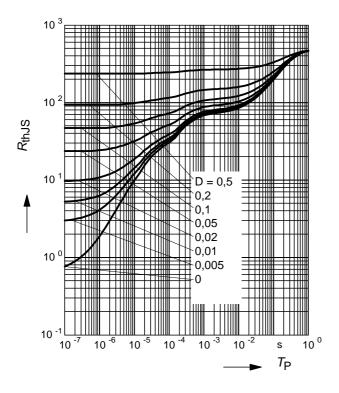
# Forward current $I_F = f(T_S)$

BAV70W



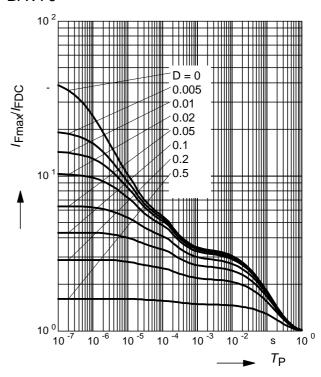


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAV70

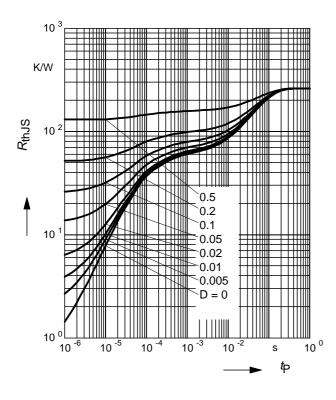


#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV70

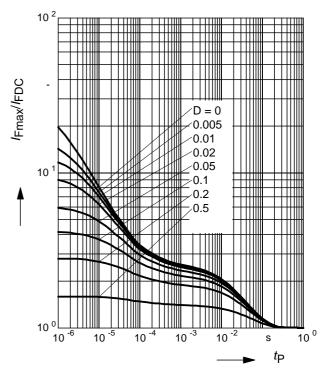


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAV70S



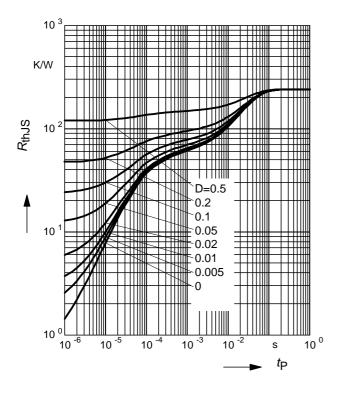
#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV70S



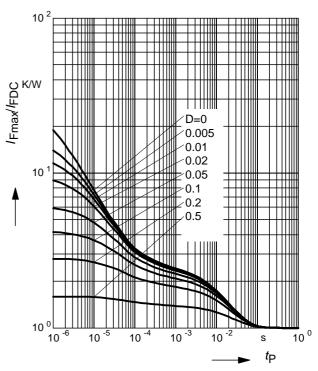


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAV70U

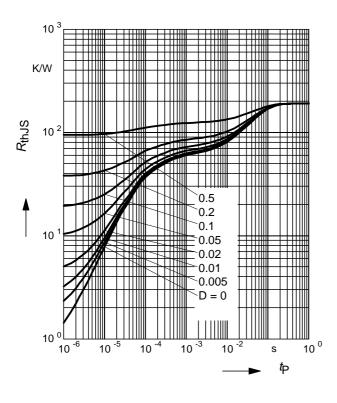


#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV70U

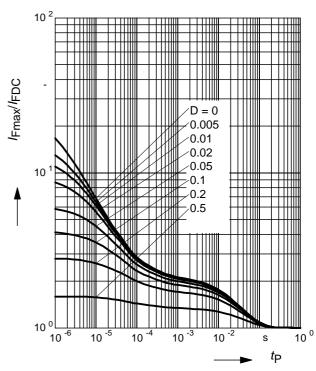


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAV70W

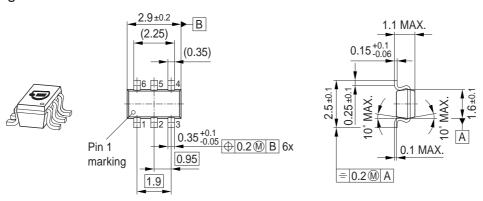


#### **Permissible Pulse Load**

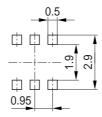
 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV70W





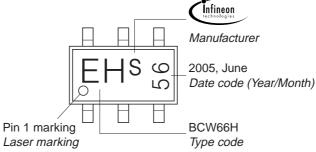


#### Foot Print



## Marking Layout (Example)

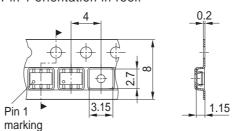
Small variations in positioning of Date code, Type code and Manufacture are possible.



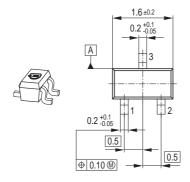
# Standard Packing

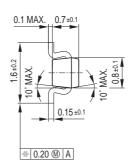
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.

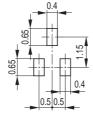




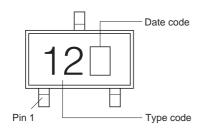


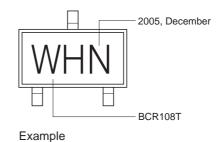


#### Foot Print



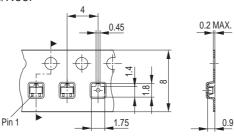
#### Marking Layout





# Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





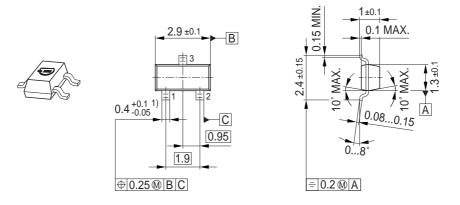
# Date Code marking for discrete packages with one digit (SCD80, SC79, SC751) CES-Code

Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	а	р	Α	Р	а	р	Α	Р	а	р	Α	Р
02	b	q	В	Q	b	q	В	Q	b	q	В	Q
03	С	r	С	R	С	r	С	R	С	r	С	R
04	d	S	D	S	d	S	D	S	d	S	D	S
05	е	t	Е	T	е	t	Е	Т	е	t	Е	Т
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	٧	G	V	g	٧	G	V	g	٧	G	V
08	h	Х	Η	Х	h	Х	Н	Х	h	Х	Η	X
09	j	у	7	Υ	j	у	7	Υ	j	у	J	Υ
10	k	Z	K	Z	k	Z	K	Z	k	Z	K	Z
11	I	2	L	4	I	2	L	4	I	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

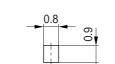
<sup>1)</sup> New Marking Layout for SC75, implemented at October 2005.

10 2006-01-17





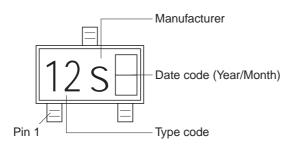
Foot Print

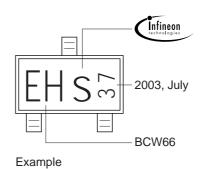


1) Lead width can be 0.6 max. in dambar area

# 0.8 1.2 00

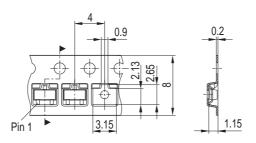
#### Marking Layout





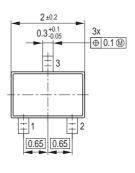
# Standard Packing

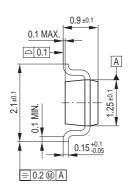
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



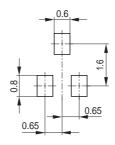




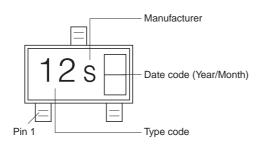


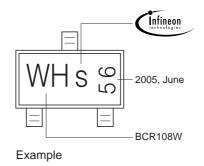


#### Foot Print



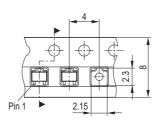
#### Marking Layout





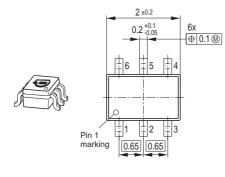
# Standard Packing

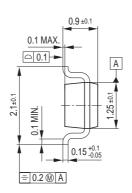
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



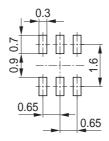






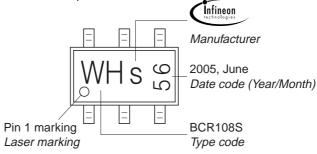


#### Foot Print



### Marking Layout (Example)

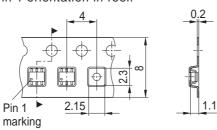
Small variations in positioning of Date code, Type code and Manufacture are possible.



# Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.





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